NSN 5961-01-426-3253

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-426-3253 **Inclosure Material:** Glass **Overall Length:** 0.146 inches **End Application:** Missile **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.0 working peak reverse voltage **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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